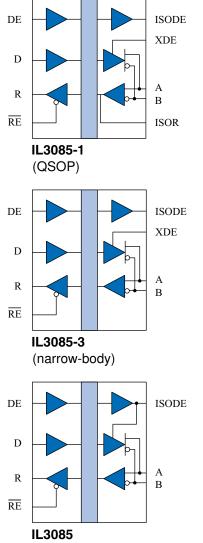


# IL3085

# Low-Cost Isolated RS-485 Transceivers

## Functional Diagrams



(wide-body)

VID (A-B)	DE	RE	R	D	Mode	Notes
$\geq 200 \text{ mV}$	L	L	Н	Х		
≤-200mV	L	L	L	Х	Receive	
Open	L	L	Н	Х		A/B failsafe
≥ 1.5 V	Н	L	Н	Н		R reads back
≤-1.5 V	Н	L	L	L	Drive	D information
≥ 1.5 V	Н	Н	Ζ	Η	Drive	R tri-state
≤-1.5 V	Н	Н	Ζ	L		(no output)
Х	L	Н	Z	X	Disabled	R tri-state; A/B failsafe

IsoLoop<sup>®</sup> is a registered trademark of NVE Corporation. \*U.S. Patent number 5,831,426; 6,300,617 and others.

## Features

- 4 Mbps data rate
- Supports up to 32 nodes
- 3 V to 5 V power supplies
- 50 kV/µs typ.; 30 kV/µs min. common mode transient immunity
- Low quiescent supply current
- 44000 year barrier life
- 7 kV bus ESD protection
- Low EMC footprint
- Thermal shutdown protection
- -40 °C to +85 °C and -40 °C to +125 °C versions
- Meets or exceeds ANSI RS-485 and ISO 8482:1987(E)
- 2500 V<sub>RMS</sub> isolation voltage per UL 1577
- VDE V 0884-11/IEC 60747-17:2020 certified; UL 1577 recognized
- QSOP, 0.15" SOIC, and 0.3" True 8™ mm 16-pin SOIC packages

## Applications

- Factory automation
- Industrial control networks
- Building environmental controls
- Equipment covered under IEC 61010-1 Edition 3
- 5 kV<sub>RMS</sub> rated IEC 60601-1 medical applications

# Description

The IL3085 is a galvanically isolated, high-speed differential bus transceiver, designed for bidirectional data communication on balanced transmission lines. The device uses NVE's patented\* spintronic Giant Magnetoresistance (GMR) technology.

A unique ceramic/polymer composite barrier provides excellent isolation and virtually unlimited barrier life.

The wide-body version provides true 8 mm creepage. Narrow-body and QSOP packages offer unprecedented miniaturization.

The IL3085 delivers at least 1.5 V into a 27  $\Omega$  load for excellent data integrity over long cable lengths. The device is compatible with 3.3 V input supplies, allowing interface to standard microcontrollers without additional level shifting.

Current limiting and thermal shutdown features protect against output short circuits and bus contention that may cause excessive power dissipation. Receiver inputs feature a "fail-safe if open" design, ensuring a logic high R-output if A/B are floating.





## Absolute Maximum Ratings<sup>(6)</sup>

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Storage Temperature	Ts	-55		150	°C	
Junction Temperature	TJ	-55		150	°C	
Voltage Range at A or B Bus Pins		-8		12.5	V	
Supply Voltage <sup>(1)</sup>	$V_{DD1}, V_{DD2}$	-0.5		7	V	
Digital Input Voltage		-0.5		$V_{DD} + 0.5$	V	
Digital Output Voltage		-0.5		V <sub>DD</sub> + 1	V	
ESD (all bus nodes)		7			kV	HBM

# **Recommended Operating Conditions**

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions
Supply Voltage	$V_{DD1} V_{DD2}$	3.0 4.5		5.5 5.5	V	
Ambient Operating Temperature IL3085-1E, IL3085-3E, IL3085E IL3085TE	T <sub>A</sub>	-40		85 125	°C	
Junction Temperature IL3085-1E, IL3085-3E, IL3085E IL3085TE	TJ	-40		100 140	°C	
Input Voltage at any Bus Terminal (separately or common mode)	Vi Vic			12 -7	V	
High-Level Digital Input Voltage	$\mathbf{V}_{\mathrm{IH}}$	2.4 3.0		$V_{\text{DD1}}$	V	$V_{DD1} = 3.3 V$ $V_{DD1} = 5.0 V$
Low-Level Digital Input Voltage	VIL	0		0.8	V	
Differential Input Voltage <sup>(2)</sup>	$V_{ID}$			+12/-7	V	
High-Level Output Current (Driver)	Іон			60	mA	
High-Level Digital Output Current (Receiver)	Іон			8	mA	
Low-Level Output Current (Driver)	Iol	-60			mA	
Low-Level Digital Output Current (Receiver)	Iol	-8			mA	
Digital Input Signal Rise and Fall Times	t <sub>IR</sub> , t <sub>IF</sub>			DC St	able	

## **Insulation Specifications**

Parameter			Symbol	Min.	Тур.	Max.	Units	Test Conditions
	IL3085-1	1		3.2				
Creepage Distance	IL3085-3	3		4.0			mm	
(external)	IL3085			8.03	8.3			Per IEC 60601
Total Barrier Thickn	ess (intern	al)		0.012	0.013		mm	
Barrier Resistance			R <sub>IO</sub>		>10 <sup>14</sup>		Ω	500 V
Barrier Capacitance			CIO		7		pF	f = 1 MHz
Leakage Current					0.2		μA <sub>rms</sub>	240 V <sub>RMS</sub> , 60 Hz
Comparative Trackin	ng Index		CTI	≥175			V	Per IEC 60112
High Voltage Endur	ance	AC		1000			V <sub>RMS</sub>	At maximum
(Maximum Barrier V	Voltage		V <sub>IO</sub>					
for Indefinite Life)		DC		1500			$V_{\text{DC}}$	operating temperature
Barrier Life				44000		Years	100°C, 1000 V <sub>RMS</sub> , 60%	
					44000		reals	CL activation energy



## Safety and Approvals

IEC 60747-17 (VDE 0884-17):2021-10 (Basic Isolation; VDE File Number 5016933-4880-0001):

- Isolation voltage (V<sub>ISO</sub>): 2500 V<sub>RMS</sub>
- Transient overvoltage (VIOTM): 4000 VPK
- Surge rating 4000 V
- Each part tested at 1590 VPK for 1 second, 5 pC partial discharge limit
- Samples tested at 4000 VPK for 60 sec.; then 1358 VPK for 10 sec. with 5 pC partial discharge limit

IL3085

• Working Voltage (V<sub>IORM</sub>; pollution degree 2):

Package	Part No. Suffix	Working Voltage
QSOP16	-1	600 V <sub>RMS</sub>
Narrow-body SOIC16	-3	700 V <sub>RMS</sub>
Wide-body SOIC16/True 8 <sup>TM</sup>	None	600 V <sub>RMS</sub>

Safety-Limiting Values	Symbol	Value	Units
Safety rating ambient temperature	Ts	180	°C
Safety rating power (180°C)	Ps	270	mW
Supply current safety rating (total of supplies)	Is	54	mA

UL 1577 (Component Recognition Program File Number E207481)

Each part tested at 3000 V<sub>RMS</sub> (4240 V<sub>PK</sub>) for 1 second; each lot sample tested at 2500 V<sub>RMS</sub> (3530 V<sub>PK</sub>) for 1 minute

## Soldering Profile

Per JEDEC J-STD-020C, MSL 1

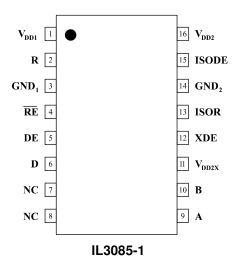


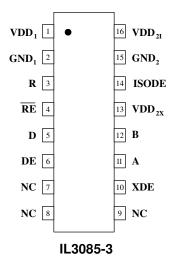
## IL3085-1 (QSOP Package) Pin Connections

1	V <sub>DD1</sub>	Input power supply
2	R	Output data from bus
3	GND <sub>1</sub>	Input power supply ground return
4	RE	Read data enable (if RE is high, R= high impedance)
5	DE	Drive enable
6	D	Data input to bus
7, 8	NC	No internal connection
9	А	Non-inverting bus line
10	В	Inverting bus line
11	V <sub>DD2X</sub>	Output transceiver power supply (normally connected to pin 16)
12	XDE	Transceiver Device Enable input enables the transceiver from the bus side, or is connected to ISODE to enable the trans- ceiver from the controller-side DE input. (this input should not be left unterminated)
13	ISOR	Isolated R output (for testing; no connection should be made to this pin)
14	GND <sub>2</sub>	Output power supply ground return.
15	ISODE	Isolated DE output (normally connected to pin 12)
16	V <sub>DD2I</sub>	Output isolation power supply (normally connected to pin 11)



L3065-3 (0.15 SOIC Package) Pin Connections							
1	V <sub>DD1</sub>	Input power supply					
2	GND1	Input power supply ground return					
3	R	Output data from bus					
4	RE	Read data enable (if RE is high, R= high impedance)					
5	D	Data input to bus					
6	DE	Drive enable					
7, 8, 9	NC	No internal connection					
10	XDE	Transceiver Device Enable input enables the transceiver from the bus side, or is connected to ISODE to enable the trans- ceiver from the controller-side DE input. (this input should not be left unterminated)					
11	А	Non-inverting bus line					
12	В	Inverting bus line					
13	V <sub>DD2X</sub>	Output transceiver power supply (normally connected to pin 16)					
14	ISODE	Isolated DE output (normally connected to pin 10)					
15	GND <sub>2</sub>	Output power supply ground return.					
16	V <sub>DD2I</sub>	Output isolation power supply (normally connected to pin 13)					

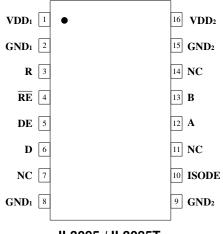






# IL3085 / IL3085T (0.3" SOIC Package) Pin Connections

1	V <sub>DD1</sub>	Input power supply
2	GND <sub>1</sub>	Input power supply ground return (pin 2 is internally connected to pin 8)
3	R	Output data from bus
4	RE	Read data enable (if RE is high, R= high impedance)
5	DE	Drive enable
6	D	Data input to bus
7	NC	No internal connection
8	GND <sub>1</sub>	Input power supply ground return (pin 8 is internally connected to pin 2)
9	GND <sub>2</sub>	Output power supply ground return (pin 9 is internally connected to pin 15)
10	ISODE	Isolated DE output for use in PROFIBUS applications where the state of the isolated drive enable node needs to be monitored.
11	NC	No internal connection
12	А	Non-inverting bus line
13	В	Inverting bus line
14	NC	No internal connection
15	GND <sub>2</sub>	Output power supply ground return (pin 15 is internally connected to pin 9)
16	V <sub>DD2</sub>	Output power supply



IL3085 / IL3085T



## **Driver Section**

<b>Electrical Specifications</b> ( $T_{min}$ to $T_{max}$ and $V_{DD} = 4.5$ V to 5.5 V unless otherwise stated)								
Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions		
Output voltage	Vo			V <sub>DD</sub>	V	$I_0 = 0$		
Differential Output Voltage <sup>(2)</sup>	V <sub>OD1</sub>			V <sub>DD</sub>	V	$I_0 = 0$		
Differential Output Voltage <sup>(2)</sup>	V <sub>OD3</sub>	1.5	2.3	5	V	$R_{\rm L} = 54 \ \Omega, \ V_{\rm DD} = 4.5 \ V$		
Change in Magnitude of Differential Output Voltage <sup>(3)</sup>	$\Delta  V_{\text{OD}} $		±0.01	±0.2	v	$R_L = 54 \ \Omega \text{ or } 100 \ \Omega$		
Common Mode Output Voltage	Voc			3	V	$R_L = 54 \Omega \text{ or } 100 \Omega$		
Change in Magnitude of Common Mode Output Voltage <sup>(3)</sup>	$\Delta  V_{oc} $		±0.01	±0.2	V	$R_L = 54 \ \Omega \text{ or } 100 \ \Omega$		
Output Current	Io			1 -0.8	mA	Output Disabled, $V_0 = 12$ $V_0 = -7$		
High Level Input Current	I <sub>IH</sub>			10	μΑ	$V_{I} = 3.5 V$		
Low Level Input Current	IIL			-10	μΑ	$V_{I} = 0.4 V$		
Absolute  Short-circuit Output Current	Ios			250	mA	$-7 \text{ V} < \text{V}_0 < 12 \text{ V}$		
Supply Current $V_{DD1} = 5 V$ $V_{DD1} = 3.3 V$	I <sub>DD1</sub> I <sub>DD1</sub>		4 3	6 4	mA	No Load (Outputs Enabled)		

## **Receiver Section**

Electrical Spo	<b>Electrical Specifications</b> ( $T_{min}$ to $T_{max}$ and $V_{DD} = 4.5$ V to 5.5 V unless otherwise stated)								
Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions			
Positive-going Input Threshold Voltage	V <sub>IT+</sub>			0.2	v	$-7 \text{ V} < V_{\text{CM}} < 12 \text{ V}$			
Negative-going Input Threshold Voltage	V <sub>IT</sub> -	-0.2			v	$-7 \text{ V} < \text{V}_{\text{CM}} < 12 \text{ V}$			
Hysteresis Voltage (V <sub>IT+</sub> – V <sub>IT-</sub> )	V <sub>HYS</sub>		70		mV	$V_{CM} = 0 V, T = 25^{\circ}C$			
High Level Digital Output Voltage	Voh	$V_{DD}-0.2$	$V_{DD}$		v	$V_{ID} = 200 \text{ mV}$ $I_{OH} = -20 \mu \text{A}$			
Low Level Digital Output Voltage	Vol			0.2	v	$V_{ID} = -200 \text{ mV}$ $I_{OH} = 20 \mu \text{A}$			
High-Impedance-State Output Current	Ioz			±1	μΑ	$V_0 = 0.4$ to $(V_{DD2}-0.5)$ V			
Line Input Current <sup>(8)</sup>	II			1	mA	$V_{I} = 12 V$			
				-0.8	mA	$V_{I} = -7 V$			
Input Resistance	Rı	12			kΩ				
Supply Current	I <sub>DD2</sub>		5	16	mA	No load; Outputs Enabled; $V_{DD2x}$ connected to $V_{DD2I}$ if applicable			

# **Power Consumption**

$T_{min}$ to $T_{max}$ and $V_{DD2} = 5$ V unless otherwise stated									
Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions			
Controller-Side $V_{DD1} = 3.3 \text{ V}$ Quiescent Current $V_{DD1} = 5 \text{ V}$	$I_{DD1}$		3 4	4 6	mA	$f_{IN} = 0 Hz$			
Bus-Side Quiescent Supply Current	I <sub>DD2</sub>		5	16	mA	$\begin{array}{l} Outputs \ Enabled; \\ R_T = \infty; \ f_{IN} = 0 \ Hz \ ; \\ V_{DD2x} \ connected \ to \ V_{DD2I} \\ if \ applicable \end{array}$			
Controller-Side Dynamic Supply Current	I <sub>DD1</sub>		0.22			$V_{DD1} = 3.3 V$			
Bus-Side Dynamic Supply Current	$\Delta I_{\text{DD2}} / \Delta f_{\text{IN}}$		1 0.8		mA/Mbps	$R_{\rm T} = \infty$ $R_{\rm T} = 60 \ \Omega$			



# **Switching Characteristics**

	$V_{DD1} = 5 V, V_{DD2} = 5 V$						
Parameter		Symbol	Min.	Тур.	Max.	Units	Test Conditions
Data Rate			4			Mbps	$R_L = 54 \Omega, C_L = 50 pF$
Propagation Delay <sup>(4)</sup>		t <sub>PD</sub>		48	150	ns	$V_0 = -1.5$ to 1.5 V, $C_L = 15 \text{ pF}$
Pulse Skew <sup>(5)</sup>	Pulse Skew <sup>(5)</sup>			6	15	ns	$V_0 = -1.5$ to 1.5 V, $C_L = 15 \text{ pF}$
Output Enable Tim	ne To High Level	t <sub>PZH</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Output Enable Tim	ne To Low Level	t <sub>PZL</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Output Disable Tin	ne From High Level	t <sub>PHZ</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Output Disable Tir	ne From Low Level	t <sub>PLZ</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Common Mode Transient Immunity (Output Logic High to Logic Low)		CM <sub>H</sub>  , CM <sub>L</sub>	30	50		kV/μs	$V_{CM} = 1500 V_{DC}$ $t_{TRANSIENT} = 25 ns$
	$V_{DD1} = 3.3 \text{ V}, V_{DD2} = 5 \text{ V}$						
Parameter	Parameter		Min.	Тур.	Max.	Units	Test Conditions
Data Rate			4			Mbps	$R_L = 54 \Omega$ , $C_L = 50 pF$
Propagation Delay <sup>(4)</sup>	-40 to +85 °C -40 to +125 °C	$t_{PD}$		48 58	150 155	ns	$V_0 = -1.5$ to 1.5 V, $C_L = 15 \text{ pF}$
Pulse Skew <sup>(5)</sup>		t <sub>sk</sub> (P)		6	20	ns	$V_0 = -1.5$ to 1.5 V, $C_L = 15 \text{ pF}$
Output Enable Time To High Level		t <sub>PZH</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Output Enable Time To Low Level		t <sub>PZL</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Output Disable Time From High Level		t <sub>PHZ</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Output Disable Time From Low Level		t <sub>PLZ</sub>		33	50	ns	$C_L = 15 \text{ pF}$
Common Mode Transient Immunity (Output Logic High to Logic Low)		CM <sub>H</sub>  , CM <sub>L</sub>	30	50		kV/μs	$\begin{array}{l} V_{CM} = 1500 \ V_{DC} \\ t_{TRANSIENT} = 25 \ ns \end{array}$

# Magnetic Field Immunity(7)

$V_{DD1} = 5 V, V_{DD2} = 5 V$					
Power Frequency Magnetic Immunity	$H_{PF}$	3500	A/m	50Hz/60Hz	
Pulse Magnetic Field Immunity	$H_{PM}$	4500	A/m	$t_p = 8\mu s$	
Damped Oscillatory Magnetic Field	Hosc	4500	A/m	0.1Hz – 1MHz	
Cross-axis Immunity Multiplier <sup>(8)</sup>	Kx	2.5			
$V_{DD1} = 3.3 V, V_{DD2} = 5 V$					
Power Frequency Magnetic Immunity	$H_{PF}$	1500	A/m	50Hz/60Hz	
Pulse Magnetic Field Immunity	Hpm	2000	A/m	$t_p = 8\mu s$	
Damped Oscillatory Magnetic Field	Hosc	2000	A/m	0.1Hz – 1MHz	
Cross-axis Immunity Multiplier <sup>(8)</sup>	Kx	2.5			

## **Thermal Characteristics**

Parameter		Symbol	Min.	Тур.	Max.	Units	Test Conditions
Junction–Ambient Thermal Resistance	QSOP 0.15" SOIC 0.3" SOIC	$\theta_{\rm JA}$		100 82 67			Double-sided PCB in
Junction–Case (Top) Thermal Resistance	QSOP 0.15" SOIC 0.3" SOIC	$\theta_{\rm JC}$		9 8 12		°C/W	free air
Junction–Ambient Thermal Resistance	- 0.3" SOIC	$\theta_{\mathrm{JA}}$		46			2s2p PCB in free air per JESD51
Junction–Case (Top) Thermal Resistance		$\theta_{\rm JC}$		9			
Power Dissipation	QSOP 0.15" SOIC 0.3" SOIC	P <sub>D</sub>			675 700 1500	mW	



## Notes:

- 1. All voltages are with respect to network ground except differential I/O bus voltages.
- 2. Differential input/output voltage is measured at the noninverting terminal A with respect to the inverting terminal B.
- 3.  $\Delta |V_{OD}|$  and  $\Delta |V_{OC}|$  are the changes in magnitude of  $V_{OD}$  and  $V_{OC}$ , respectively, that occur when the input is changed from one logic state to the other.
- 4. Includes 10 ns read enable time. Maximum propagation delay is 25 ns after read assertion.
- 5. Pulse skew is defined as  $|t_{PLH} t_{PHL}|$  of each channel.
- 6. Absolute Maximum specifications mean the device will not be damaged if operated under these conditions. It does not guarantee performance.
- 7. The relevant test and measurement methods are given in the Electromagnetic Compatibility section on p. 9.
- 8. External magnetic field immunity is improved by this factor if the field direction is "end-to-end" rather than to "pin-to-pin."



## Electrostatic Discharge Sensitivity

This product has been tested for electrostatic sensitivity to the limits stated in the specifications. However, NVE recommends that all integrated circuits be handled with appropriate care to avoid damage. Damage caused by inappropriate handling or storage could range from performance degradation to complete failure.

## Pinout Differences Between Packages

QSOP and narrow-body version (IL3085-1E and IL3085-3E) are designed for application flexibility and minimum board area in dense PCAs. The wide-body version (IL3085E) has redundant ground pins for layout flexibility.

QSOP and narrow-body versions provide separate isolated DE output (ISODE) and Transceiver Device Enable (XDE) input. ISODE follows the Device Enable input (DE). XDE can be used to enable and disable the transceiver from the bus side, or connected to ISODE to enable and disable the transceiver from the DE controller-side input. The QSOP and narrow-body versions also provide separate bus-side power supply pins— $V_{DD2X}$  for the transceiver module and  $V_{DD21}$  for the isolation module. These should be externally connected for normal operation, but can be used separately for testing or troubleshooting. The QSOP version also has an "ISOR" output that is isolated with respect to the controller-side "R." This pin is used for testing and normally not connected, but could be used for a bus-side data output under special circumstances.

The wide-body version has internal connections between the isolated DE output and the Transceiver Device Enable input, and well as between the two  $V_{DD2}$  bus-side power supply pins. The two internally-connected GND pins for each supply side provide layout flexibility. The ISODE output can be used in PROFIBUS applications where the state of the isolated drive enable node needs to be monitored, or for testing or troubleshooting.

## **Power Supply Decoupling**

VDD1 and VDD2 should be bypassed with 0.1 µF typical (0.047 µF minimum) capacitors as close as possible to the VDD pins.

#### Maintaining Creepage

Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. Package drawings and recommended pad layouts are included in this datasheet.

## **DC Correctness**

The IL3085 incorporates a patented refresh circuit to maintain the correct output state with respect to data input. At power up, the bus outputs will follow the Function Table shown on Page 1. The DE input should be held low during power-up to eliminate false drive data pulses from the bus. An external power supply monitor to minimize glitches caused by slow power-up and power-down transients is not required.

#### **Electromagnetic Compatibility**

The IL3085 is fully compliant with IEC 61000-6-1 and IEC 61000-6-2 standards for immunity, and IEC 61000-6-3, IEC 61000-6-4, CISPR, and FCC Class A standards for emissions.

The IsoLoop Isolator's Wheatstone bridge configuration and differential magnetic field signaling ensure excellent EM immunity. Immunity to external magnetic fields is even higher if the field direction is "end-to-end" (rather than to "pin-to-pin") as shown at right.





# Application Information

Figures 1a, 1b, and 1c show typical connections to a bus and microcontroller for the three package versions. The schematics include typical termination and fail-safe resistors, and power supply decoupling capacitors:

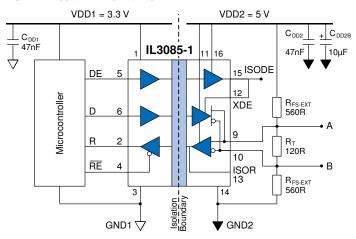


Figure 1a. Typical QSOP transceiver connections.

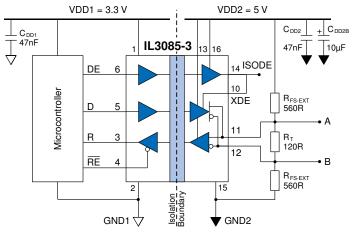


Figure 1b. Typical narrow-body connections.

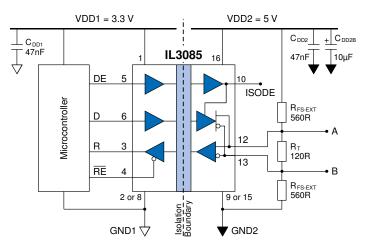


Figure 1c. Typical wide-body connections.



### **Receiver Features**

The receiver output "R" has tri-state capability via the active low  $\overline{RE}$  input.

#### Driver Features

The RS-485 driver has a differential output and delivers at least 2.1 V across a 54  $\Omega$  load. Drivers feature low propagation delay skew to maximize bit width and minimize EMI. Drivers have tri-state capability via the active-high DE input.

#### Receiver Data Rate, Cables and Terminations

The IL3085 is intended for networks up to 4,000 feet (1,200 m), but the maximum data rate decreases as cable length increases. Twisted pair cable should be used in all networks since they tend to pick up noise and other electromagnetically induced voltages as common mode signals, which are effectively rejected by the differential receiver.

## Fail-Safe Operation

"Fail-safe operation" is defined here as the forcing of a logic high state on the "R" output in response to an open-circuit condition between the "A" and "B" lines of the bus, or when no drivers are active on the bus.

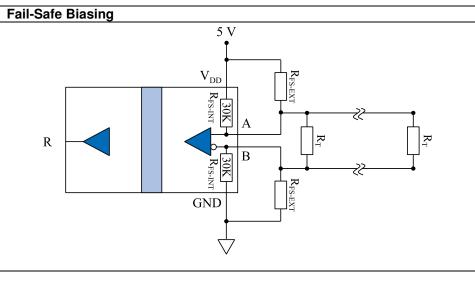
Proper biasing can ensure fail-safe operation, that is a known state when there are no active drivers on the bus. IL3000-Series Isolated Transceivers include internal pull-up and pull-down resistors of approximately  $30 \text{ k}\Omega$  in the receiver section (R<sub>FS-INT</sub>; see figure below). These internal resistors are designed to ensure failsafe operation but only if there are no termination resistors. The entire V<sub>DD</sub> will appear between inputs "A" and "B" if there is no loading and no termination resistors, and there will be more than the required 200 mV with up to four RS-485 worstcase Unit Loads of 12 k $\Omega$ . Many designs operating below 1 Mbps or less than 1,000 feet are unterminated. Termination resistors may not be necessary for very low data rates and very short cable runs because reflections have time to settle before data sampling, which occurs at the middle of the bit interval.

In busses with low-impedance termination resistors however, the differential voltage across the conductor pair will be close to zero with no active drivers. In this case the state of the bus is indeterminate, and the idle bus will be susceptible to noise. For example, with 120  $\Omega$  termination resistors (R<sub>T</sub>) on each end of the cable, and four Unit Loads (12 k $\Omega$  each), without external fail-safe biasing resistors the internal pull-up and pull-down resistors will produce a voltage between inputs "A" and "B" of only about 5 mV. This is not nearly enough to ensure a known state. External fail-safe biasing resistors (R<sub>FS-EXT</sub>) at one end of the bus can ensure fail-safe operation with a terminated bus. Resistors should be selected so that under worst-case power supply and resistor tolerances there is at least 200 mV across the conductor pair with no active drivers to meet the input sensitivity specification of the RS-485 standard.

Using the same value for pull-up and pull-down biasing resistors maintains balance for positive- and negative going transitions. Lower-value resistors increase inactive noise immunity at the expense of quiescent power consumption. Note that each Unit Load on the bus adds a worst-case loading of 12 k $\Omega$  across the conductor pair, and 32 Unit Loads add 375  $\Omega$  worst-case loading. The more loads on the bus, the lower the required values of the biasing resistors.

In the example with two 120  $\Omega$  termination resistors and four Unit Loads, 560  $\Omega$  external biasing resistors provide more than 200 mV between "A" and "B" with adequate margin for power supply variations and resistor tolerances. This ensures a known state when there are no active drivers. Other illustrative examples are shown in the following table:

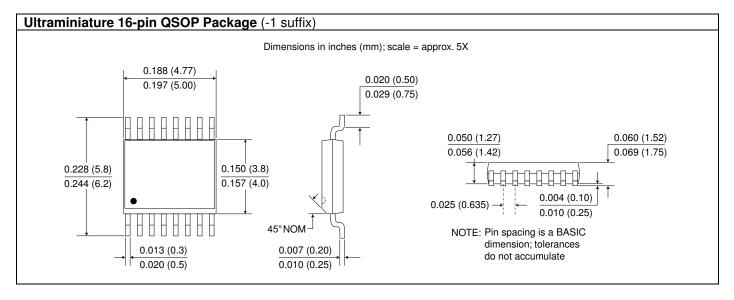


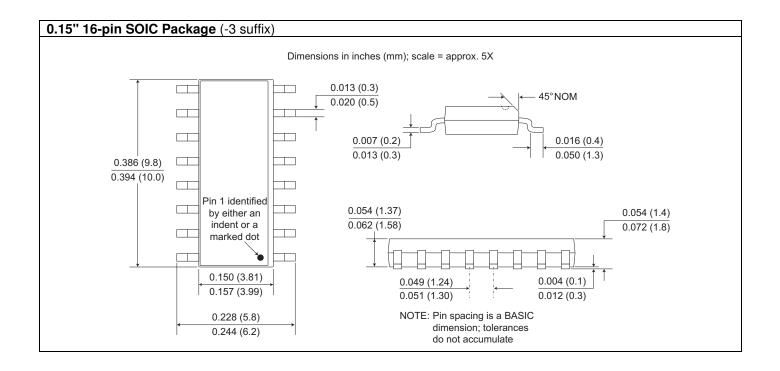


R <sub>FS-EXT</sub>	R <sub>T</sub>	Loading	Nominal V <sub>A-B</sub> (inactive)	Fail-Safe Operation?
Internal Only	None	Four unit loads (12 k $\Omega$ ea.)	238 mV	Yes
Internal Only	120 Ω	Four unit loads (12 k $\Omega$ ea.)	5 mV	No
560 Ω	120 Ω	Four unit loads (12 k $\Omega$ ea.)	254 mV	Yes
510 Ω	120 Ω	32 unit loads (12 k $\Omega$ ea.)	247 mV	Yes



## Package Drawings





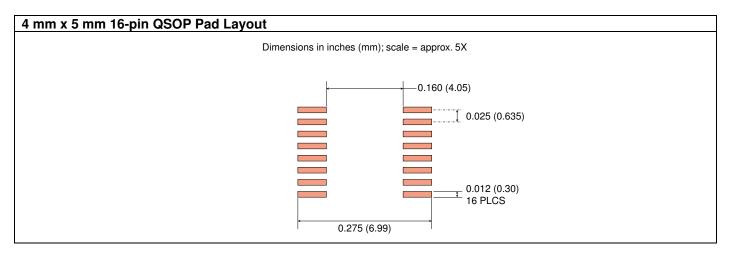


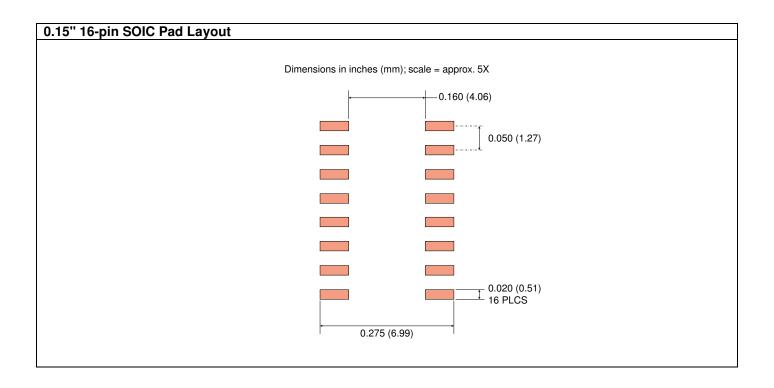


#### 0.3" 16-pin SOIC Package (no suffix) Dimensions in inches (mm); scale = approx. 5X 0.033 (0.85)\* 0.260 (6.60)\* 0.043 (1.10) 0.280 (7.11) 0.013 (0.3) 0.020 (0.5) Т 0.007 (0.2) 0.016 (0.4) 0.007 (0.18)\* 0.397 (10.08) 0.013 (0.3) 0.010 (0.25) 0.050 (1.3) 0.413 (10.49) 0.092 (2.34) Pin 1 identified by 0.105 (2.67) either an indent or a marked dot 0.017 (0.43)\* 0.08 (2.0) 0.022 (0.56) 0.10 (2.5) 2 0.292 (7.42)\* 0.004 (0.1) 0.049 (1.24) 0.299 (7.59) 0.012 (0.3) 0.051 (1.30) 0.394 (10.00) NOTE: Pin spacing is a BASIC dimension; tolerances 0.419 (10.64) do not accumulate \*Specified for True 8<sup>™</sup> package to guarantee 8 mm creepage per IEC 60601.



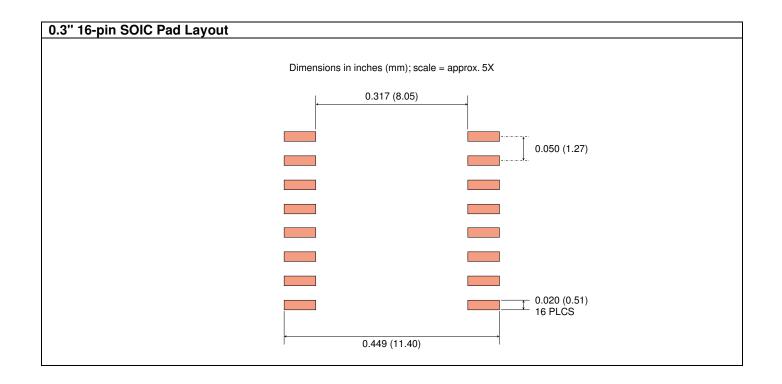
## **Recommended Pad Layouts**







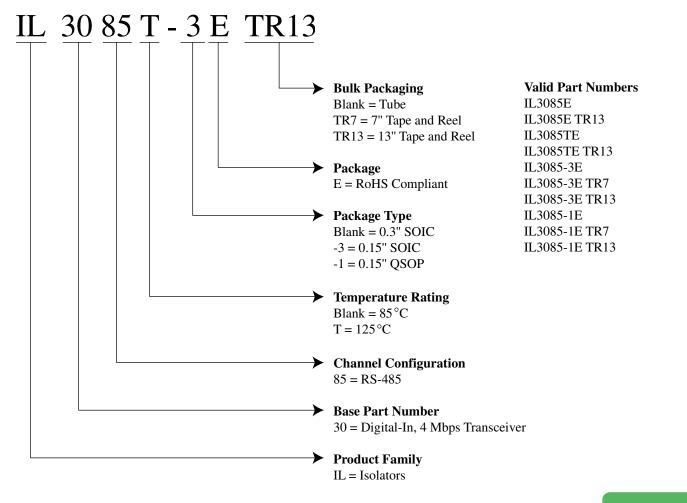






IL3085

## Ordering Information and Valid Part Numbers



RoHS COMPLIANT



**Revision History** 

Revision History	
ISB-DS-001-IL3085-J November 2023	<ul><li>Change</li><li>Added 125 °C version (IL3085TE).</li></ul>
ISB-DS-001-IL3085-I	<ul> <li>Changes</li> <li>Upgrade to VDE 0884-17 (p. 3).</li> <li>Increased Working Voltage ratings based on latest VDE testing (p. 3).</li> <li>Separate power consumption specifications section; added dynamic power consumption (p. 6).</li> <li>Updated thermal specifications (p. 7).</li> <li>Updated EMC standards.</li> </ul>
ISB-DS-001-IL3085-H	<ul><li>Change</li><li>Improved thermal specifications based on new test data (p. 2).</li></ul>
ISB-DS-001-IL3085-G	<ul> <li>Updated from IEC 60747-5-5 (VDE 0884) certification to VDE V 0884-10.</li> </ul>
ISB-DS-001-IL3085-F	<ul> <li>Change</li> <li>Increased IL3085-1E (QSOP) creepage specification from 2.75 mm to 3.2 mm (p. 2).</li> </ul>
ISB-DS-001-IL3085-E	<ul> <li>Changes</li> <li>Added QSOP version (-1 suffix).</li> <li>Revised and added details to thermal characteristic specifications (p. 2).</li> <li>Added VDE 0884 Safety-Limiting Values (p. 3).</li> </ul>
ISB-DS-001-IL3085-D	<ul> <li>Changes</li> <li>IEC 60747-5-5 (VDE 0884) certification.</li> <li>Upgraded from MSL 2 to MSL 1.</li> </ul>
ISB-DS-001-IL3085-C	<ul> <li>Changes</li> <li>Increased transient immunity specifications based on additional data.</li> <li>Noted UL 1577 recognition, IEC 61010-1 approval, and VDE 0884 pending.</li> <li>Added transient immunity specifications.</li> <li>Added high voltage endurance specification.</li> <li>Increased magnetic immunity specifications.</li> <li>Updated package outline drawings and added recommended solder pad dimensions.</li> </ul>
ISB-DS-001-IL3085-A December 2012	<ul><li>Change</li><li>Initial Release.</li></ul>



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ISB-DS-001-IL3085-J

November 2023